NSN 5961-01-076-6494

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-076-6494 **Inclosure Material:** Glass **Overall Length:** Between 0.230 inches and 0.300 inches **Terminal Length:** Between 1.000 inches and 1.500 inches **Overall Diameter:** Between 0.085 inches and 0.107 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 25.0 on-state voltage, dc and 100.0 regulator voltage **Current Rating Per Characteristic:** 1.10 amperes source cutoff current pascal **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Item must comply with requirements of defense electronics supply center production standard no. L02686; for navy nuclear propulsion plant products only; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No